

ZXMP6A13F

60V P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

V _{(BR)DSS}	R _{DS(on)}	I _D T _A = 25°C	
-60V	400mΩ @ V _{GS} = -10V	-1.1A	
-607	600mΩ @ V _{GS} = -4.5V	-0.9A	

Description and Applications

This MOSFET utilizes a unique structure that combines the benefits of low on-resistance with fast switching speed, making it ideal for high-efficiency power management applications.

- DC DC converters
- Power management functions
- Relay and solenoid driving
- Motor control

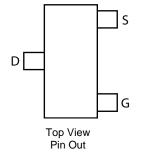
Features and Benefits

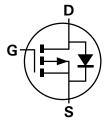
- · Fast switching speed
- Low input capacitance
- Low gate charge
- "Lead Free", RoHS Compliant (Note 1)
- Halogen and Antimony Free. "Green" Device (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish annealed over Copper leadframe Solderable per MIL-STD-202, Method 208
- Weight: 0.008 grams (approximate)

SOT23





Top View

Equivalent Circuit

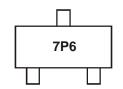
Ordering Information (Note 3)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXMP6A13FTA	7P6	7	8	3000 Units

Notes:

- 1. No purposefully added lead
- 2. Diodes Inc's "Green" policy can be found on our website at http://www.diodes.com.
- 3. For packaging details, go to our website at http://www.diodes.com.

Marking Information



7P6 = Product Type Marking Code



Maximum Ratings @T_A = 25℃ unless otherwise specified

Characteristic			Symbol	Value	Units
Drain-Source Voltage	Drain-Source Voltage			-60	V
Gate-Source Voltage			V_{GS}	±20	V
Continuous Drain Current	V _{GS} = 10V	(Note 5) T _A = 70℃ (Note 5) (Note 4)	I_{D}	-1.1 -0.8 -0.9	А
Pulsed Drain Current (Note 6)			I_{DM}	-4.0	А
Continuous Source Current (Body Diode) (Note 5)			I _S	-1.2	A
Pulsed Source Current (Body Diode) (Note 6)			I _{SM}	-4.0	A

Thermal Characteristics $@T_A = 25\%$ unless otherwise specified

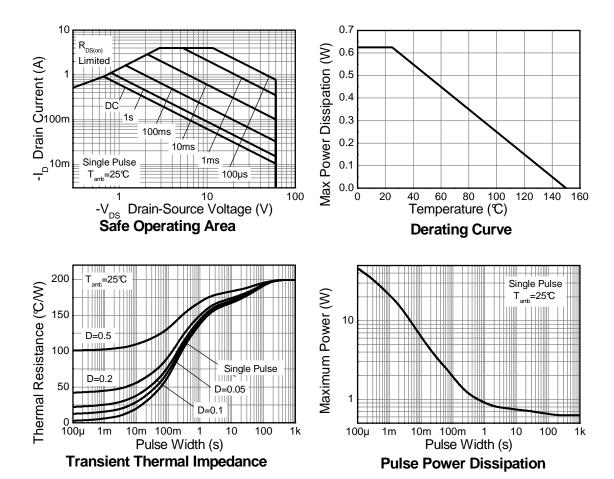
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 4)	D	625	mW
Linear Derating Factor	P _D	5	mW/℃
Power Dissipation (Note 5)	Б	806	mW
Linear Derating Factor	P _D	6.5	mW/℃
Thermal Resistance, Junction to Ambient (Note 4)	$R_{ heta JA}$	200	C/M
Thermal Resistance, Junction to Ambient (Note 5)	R _{0JA}	155	C/M
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	C

Notes:

- 4. For a device surface mounted on 25mm x 25mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions 5. For a device surface mounted on FR4 PCB measured at t ≤ 5 secs.
- 6. Repetitive rating 25mm x 25mm FR4 PCB, D = 0.05 pulse width =10µs pulse current limited by maximum junction temperature.



Thermal Characteristics







ZXMP6A13F

Electrical Characteristics @T_A = 25°C unless otherwise specified

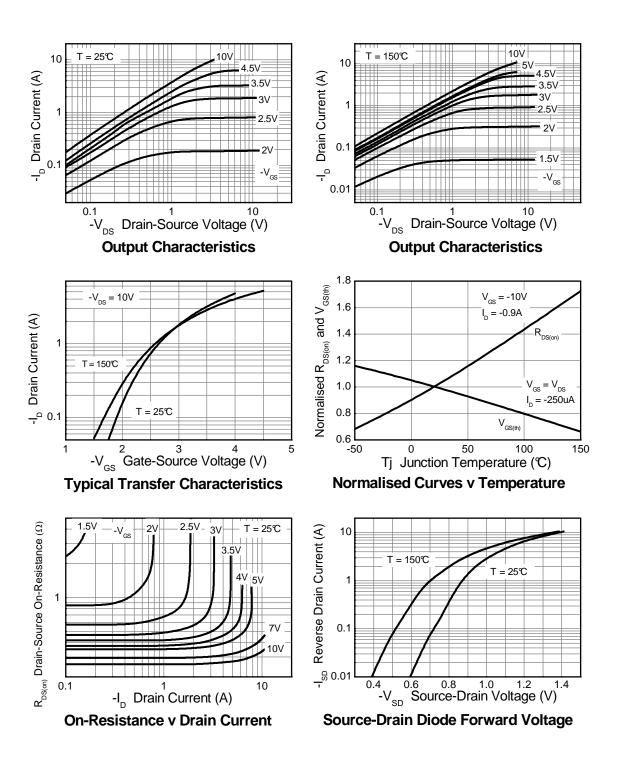
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV _{DSS}	-60	_	_	V	$I_D = -250 \mu A$, $V_{GS} = 0 V$
Zero Gate Voltage Drain Current	I _{DSS}	_	_	-0.5	μΑ	$V_{DS} = -60V, V_{GS} = 0V$
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS						
Gate Threshold Voltage	$V_{GS(th)}$	-1.0	_	-3.0	V	$I_D = -250 \mu A, V_{DS} = V_{GS}$
Static Drain-Source On-Resistance (Note 7)	R _{DS (ON)}	_		0.400	Ω	$V_{GS} = -10V, I_D = -0.9A$
Static Brain Godice On Resistance (Note 1)	INDS (ON)			0.600	32	$V_{GS} = -4.5V, I_D = -0.8A$
Forward Transconductance (Notes 7 and 9)	g _{fs}	_	1.8	_	S	$V_{DS} = -15V$, $I_{D} = -0.9A$
Diode Forward Voltage (Note 7)	V_{SD}	_	-0.85	-0.95	V	$T_J = 25$ °C, $I_S = -0.8$ A, $V_{GS} = 0$ V
Reverse Recovery Time (Note 9)	t _{rr}	_	21.1	_	ns	$T_J = 25^{\circ}C$, $I_F = -0.9A$,
Reverse Recovery Charge (Note 9)	Q _{rr}	_	19.3	_	nC	di/dt = 100A/μs
DYNAMIC CHARACTERISTICS (Note 9)						
Input Capacitance	C _{iss}	_	219	_		$V_{DS} = -30V, V_{GS} = 0V$ f = 1.0MHz
Output Capacitance	Coss	_	25.7	_	pF	
Reverse Transfer Capacitance	C _{rss}	_	20.5	_		
Turn-On Delay Time (Note 8)	t _{D(on)}	_	1.6	_		
Turn-On Rise Time (Note 8)	t _r	_	2.2	_	ns	$V_{DD} = -30V, I_D = -1A,$ $R_G \cong 6.0\Omega, \ V_{GS} = -10V$
Turn-Off Delay Time (Note 8)	t _{D(off)}	_	11.2	_	115	
Turn-Off Fall Time (Note 8)	t _f	_	5.7	_		
Total Gate Charge (Note 8)	Qg	_	2.9	_	nC	$V_{DS} = -30V, V_{GS} = -4.5V,$ $I_{D} = -0.9A$
Total Gate Charge (Note 8)	Qg	_	5.9	_		
Gate-Source Charge (Note 8)	Qgs	_	0.74		nC	$V_{DS} = -30V, V_{GS} = -10V,$ $I_{D} = -0.9A$
Gate-Drain Charge (Note 8)	Q _{gd}	_	1.5	_		U = -0.3A

Notes:

^{7.} Measured under pulsed conditions. Pulse width = $300\mu s$. Duty cycle $\leq 2\%$. 8. Switching characteristics are independent of operating junction temperature. 9. For design aid only, not subject to production testing.

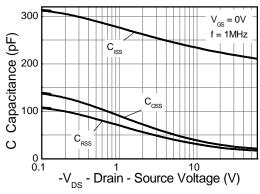


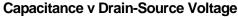
Typical Characteristics

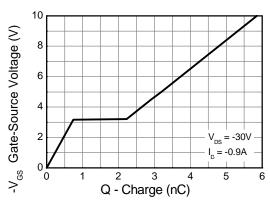




Typical Characteristics - continued

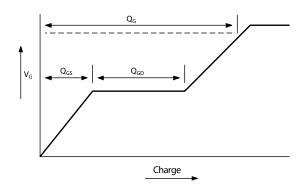




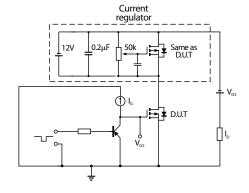


Gate-Source Voltage v Gate Charge

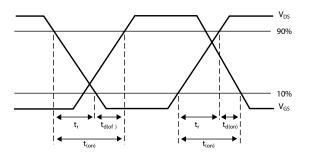
Test Circuits



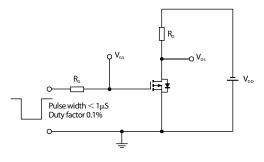
Basic gate charge waveform



Gate charge test circuit



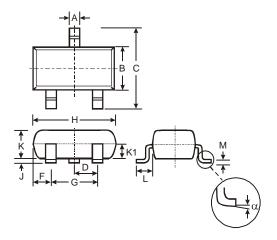
Switching time waveforms



Switching time test circuit

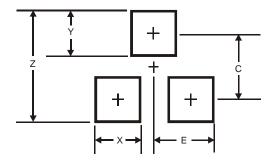


Package Outline Dimensions



SOT23					
Dim	Min	Max	Тур		
Α	0.37	0.51	0.40		
В	1.20	1.40	1.30		
С	2.30	2.50	2.40		
D	0.89	1.03	0.915		
F	0.45	0.60	0.535		
G	1.78	2.05	1.83		
Н	2.80	3.00	2.90		
J	0.013	0.10	0.05		
K	0.903	1.10	1.00		
K1	-		0.400		
L	0.45	0.61	0.55		
M	0.085	0.18	0.11		
α	0°	8°	-		
All Dimensions in mm					

Suggested Pad Layout



Dimensions	Value (in mm)		
Z	2.9		
Х	0.8		
Y	0.9		
С	2.0		
Е	1.35		





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